



Strain field and coherent domain wall effects on the thermal conductivity and Kapitza conductance in Bismuth Ferrite

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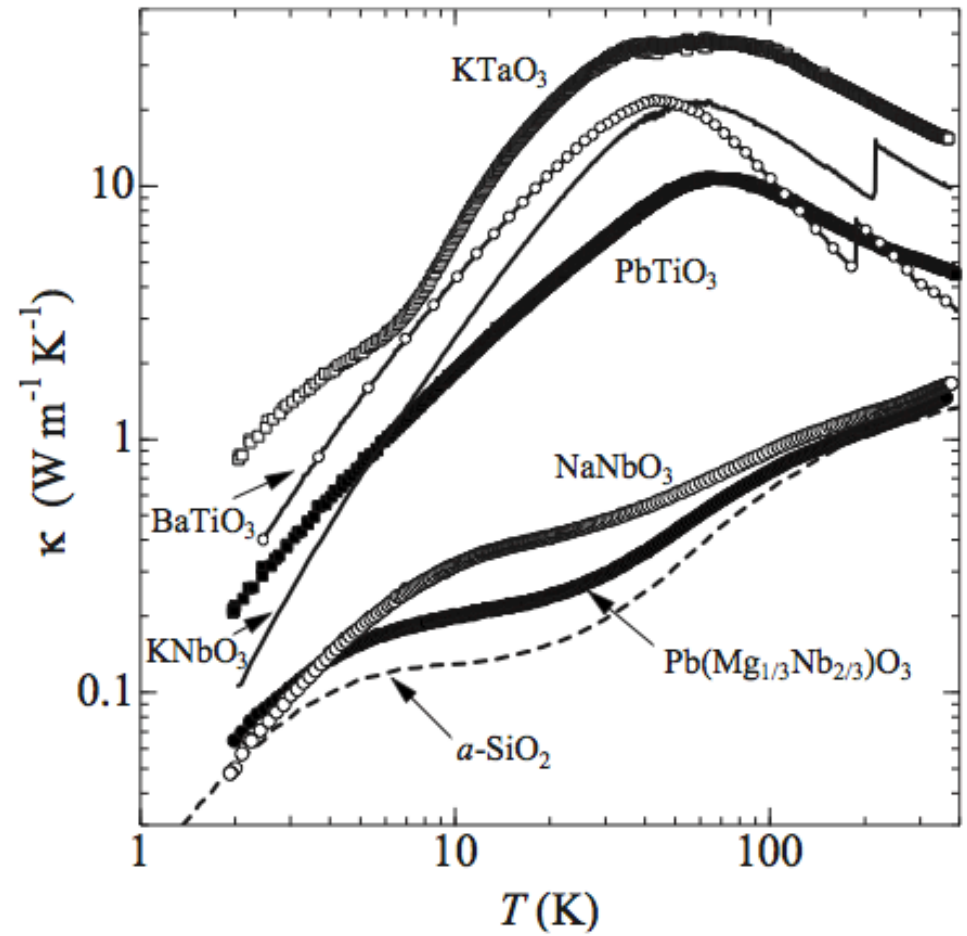
Stephen R. Lee, Doug Medlin, Harlan Brown-Shaklee,

Jon F. Ihlefeld

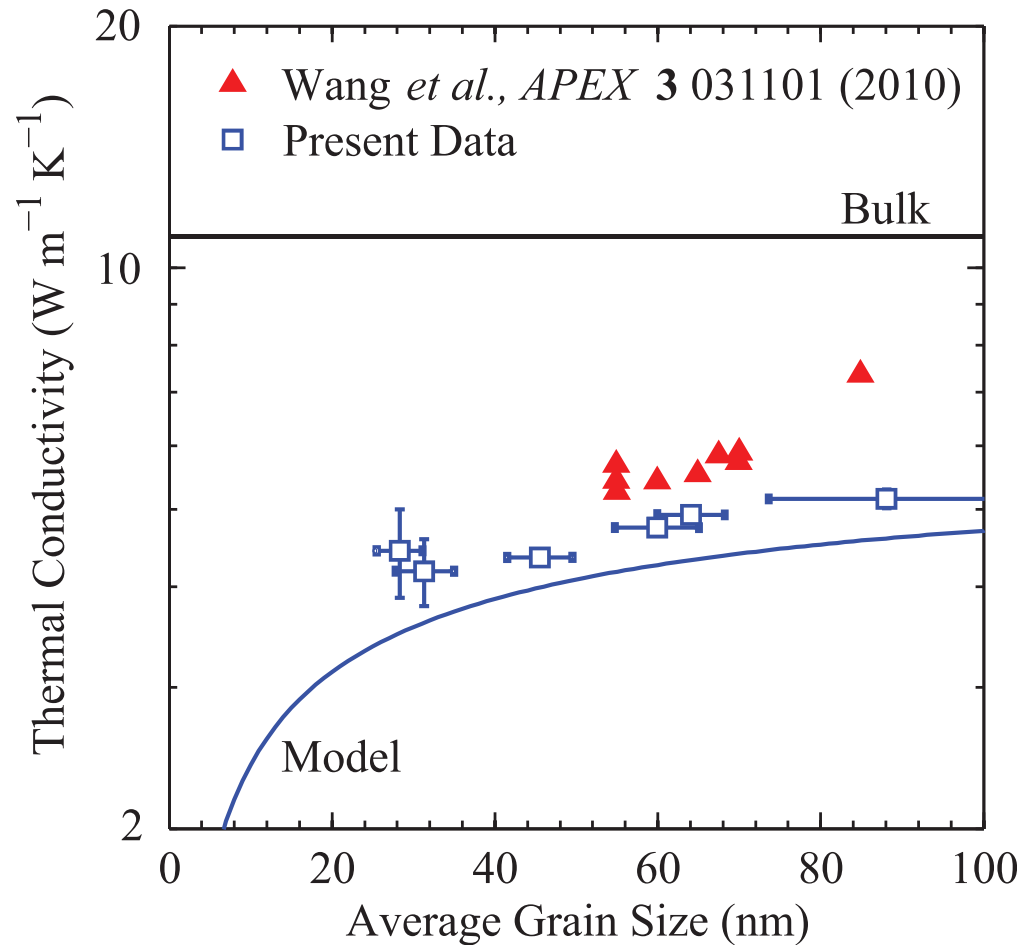
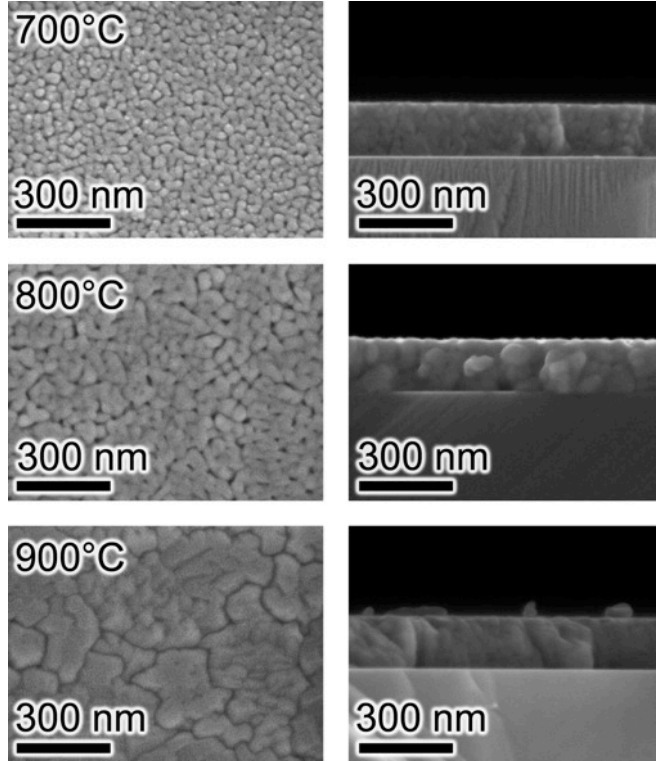
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Thermal conductivity of Ferroelectrics

- Ferroelectrics and related materials can have low thermal conductivities
 - Complex phonon spectra
 - Soft modes
 - Anisotropy
- What role do internal boundaries/structures play??



Grain boundaries: SrTiO₃



$$\tau_j = \left[\frac{1}{\tau_a} + \frac{1}{\tau_{gb}} + \frac{1}{\tau_{fb}} \right]^{-1}$$

$$= \left[BT\omega_j^2 \exp\left(-\frac{C}{T}\right) + \frac{v_j}{d_{avg}} - \frac{v_j}{170 \times 10^{-9}} \right]^{-1}$$

Foley *et al.* *Appl. Phys. Lett.* **101**, 231908 (2012)

What about domain boundaries/strain?

Grain boundaries = incoherent

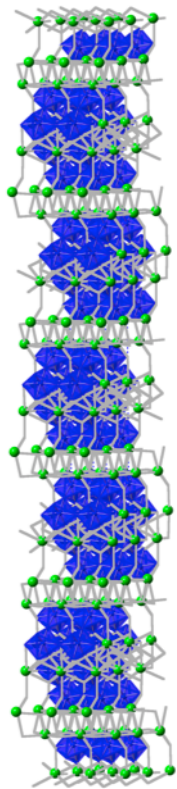
Ferroelectric domain boundaries = coherent and strained

- Domains and domain walls in BiFeO_3
- Time domain thermoreflectance (TDTR)
- Domain effects on thermal transport in BiFeO_3
- “Domain wall” Kapitza conductance – phonon-strain field scattering

“Coherent interfaces” – think layers

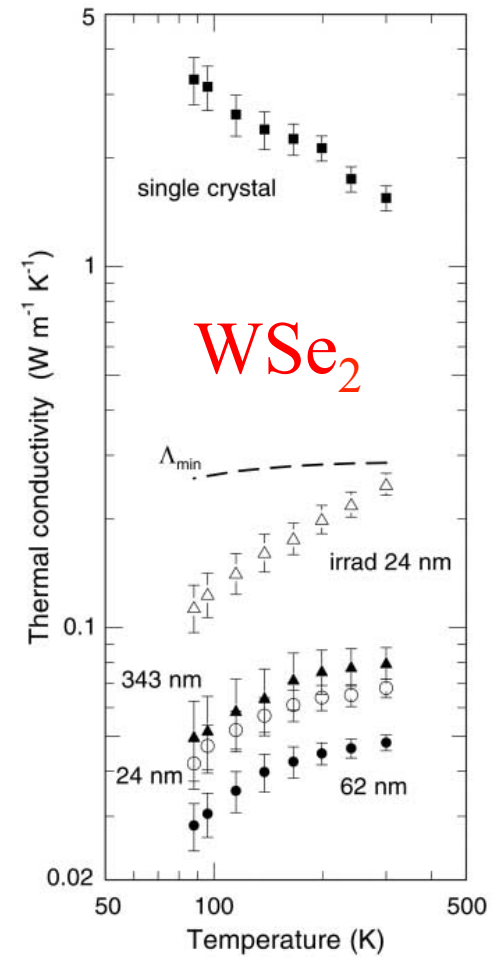
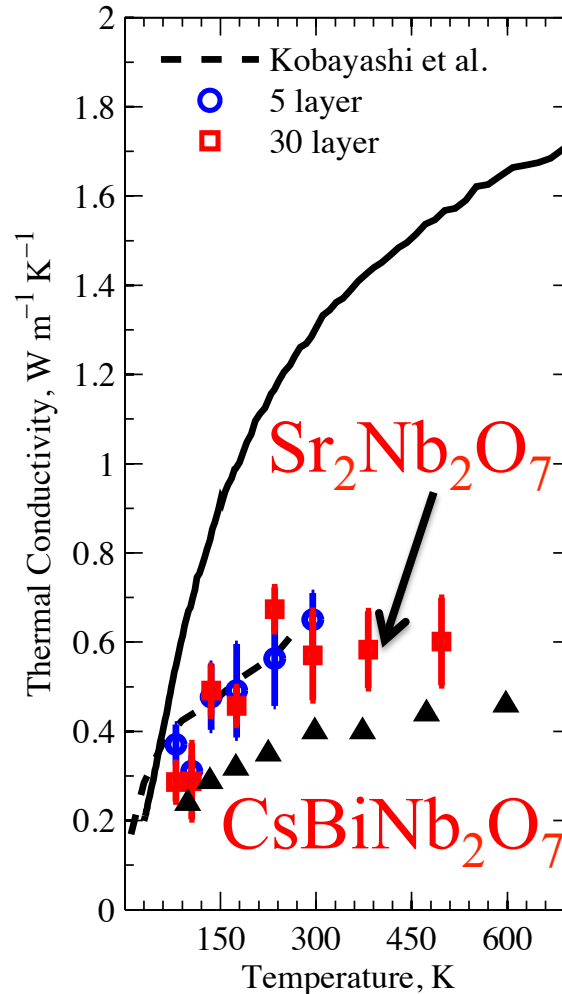
- Layered structures can exhibit ultralow thermal conductivity

Ex. $\text{Sr}_2\text{Nb}_2\text{O}_7$



} Perovskite-like layers

↳ SrO layer

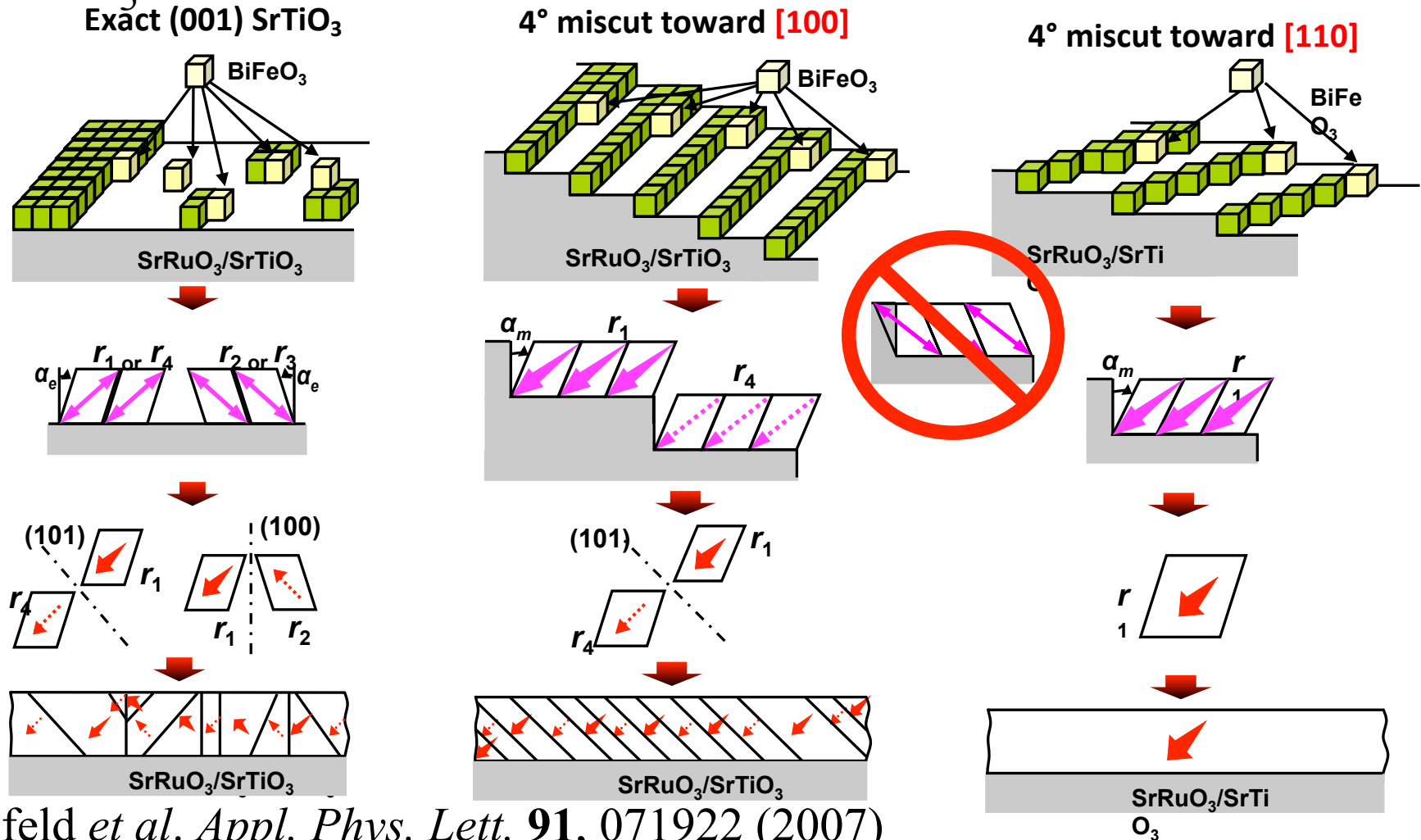


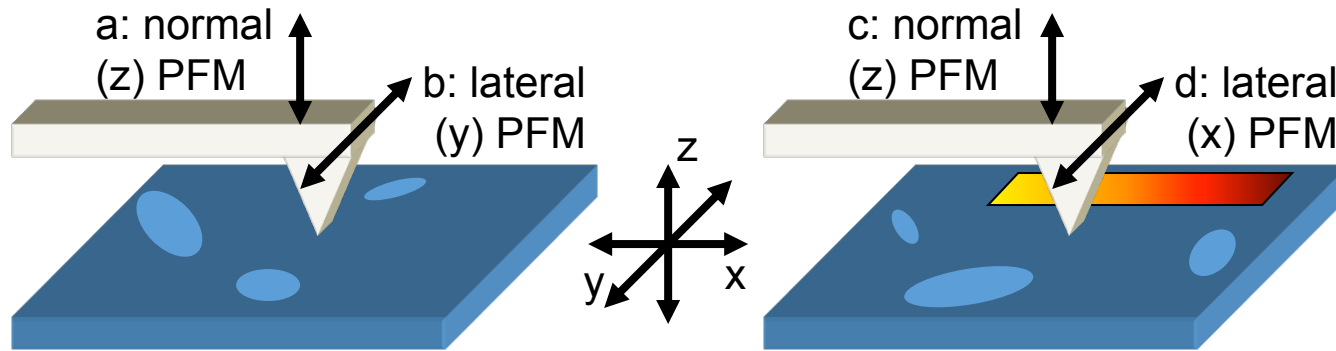
Cahill *et al.* *Appl. Phys. Lett.* **96**, 121903 (2010)

Chiritescu *et al.* *Science* **315**, 351 (2007)

“Coherent” interfaces – BiFeO₃ domains

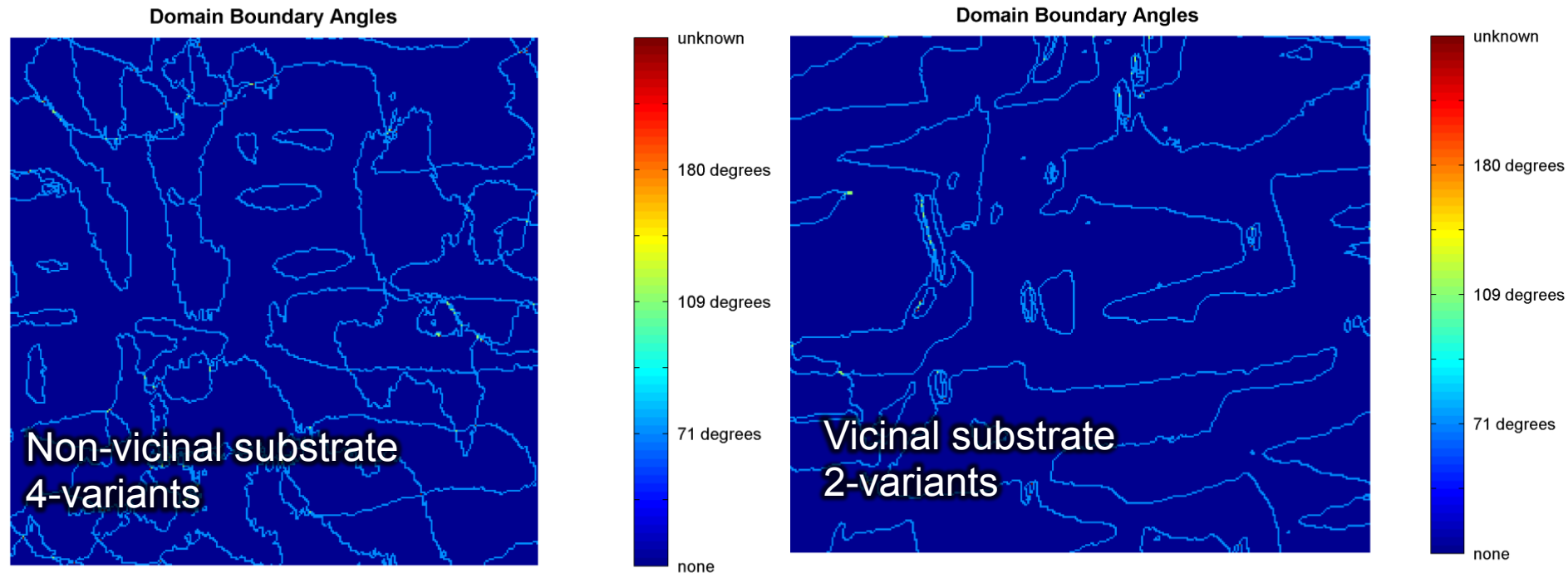
- Domain boundaries – other types of coherent interfaces
- Reactive molecular-beam epitaxy: 30 nm BiFeO₃ films on SrTiO₃ substrates





- Standard domain imaging not sufficient
- Require quantification of domain boundaries
- Vector (angle-resolved) PFM: 2 steps
 - Out-of-plane (normal) z-direction
 - In-plane y-direction
 - Rotate specimen 90 degrees

Domain boundary quantification

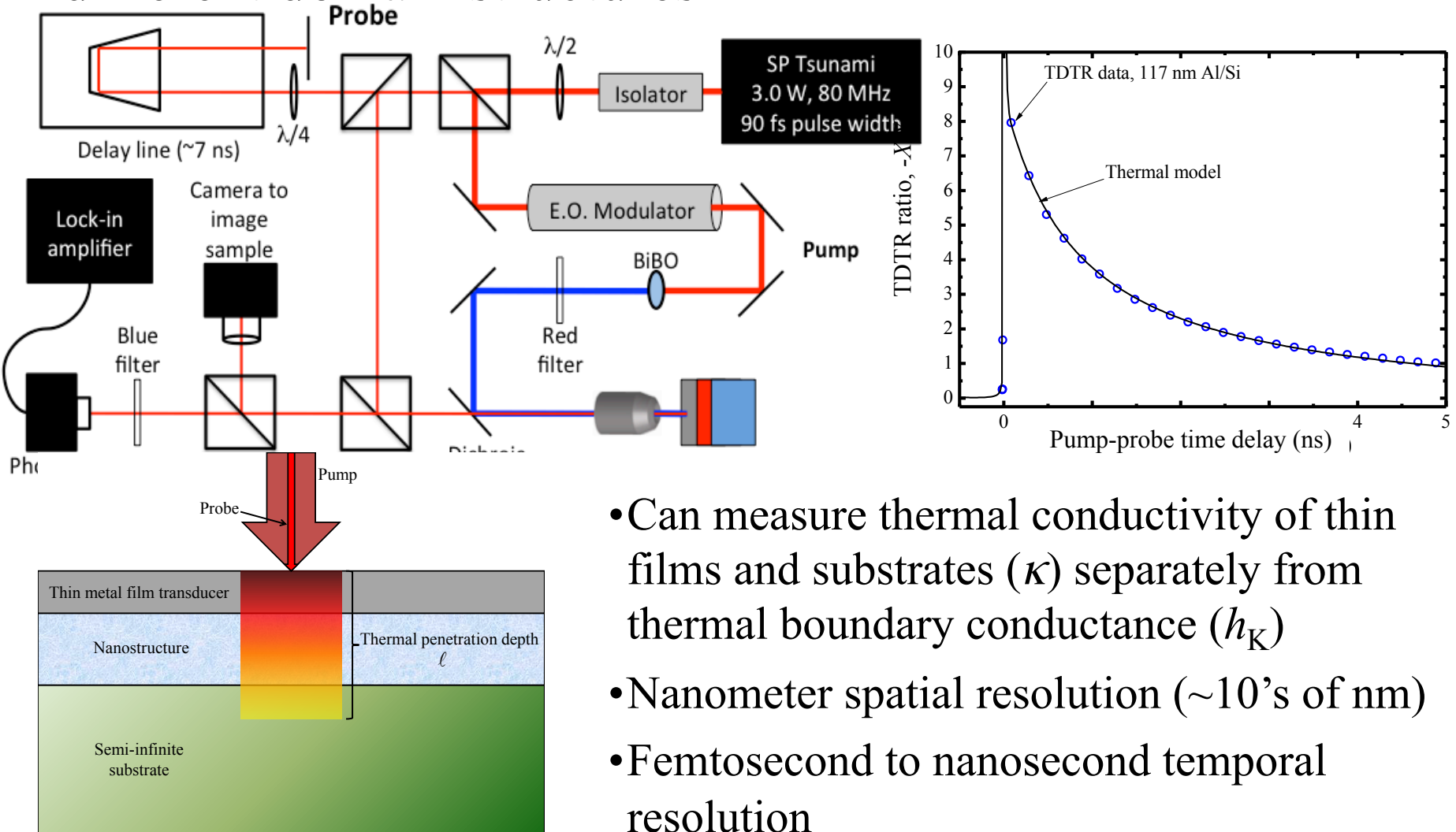


- Growth on vicinal substrate results in different domain structure
- Virtually all 71 deg. domain walls
- **4 variant: 16 μm domain wall/ μm^2**
- **2 variant: 11 μm domain wall/ μm^2**

Hopkins *et al. Appl. Phys. Lett.* **102**, 121903 (2013)

Time domain thermoreflectance (TDTR)

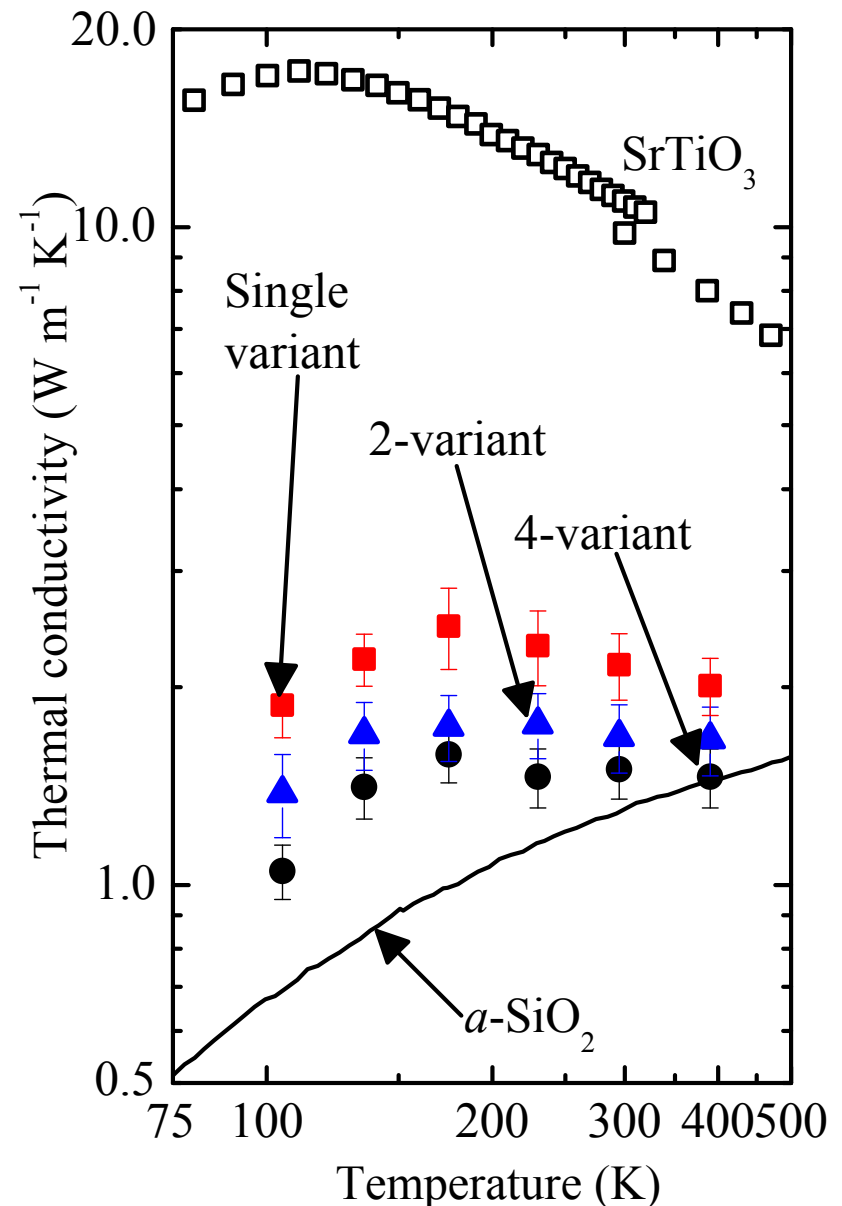
- Thermal conductivity of series of BiFeO_3 films with different domain structures



- Can measure thermal conductivity of thin films and substrates (κ) separately from thermal boundary conductance (h_K)
- Nanometer spatial resolution (~10's of nm)
- Femtosecond to nanosecond temporal resolution
- Noncontact

Domain effects on *effective* thermal conductivity

- Effective thermal conductivities of $\text{BiFeO}_3 < 2.5 \text{ W m}^{-1} \text{ K}^{-1}$
- Presence of domain walls reduces κ by $\sim 30\%$
- *Strain fields from domains are scattering phonons (previous speaker)*

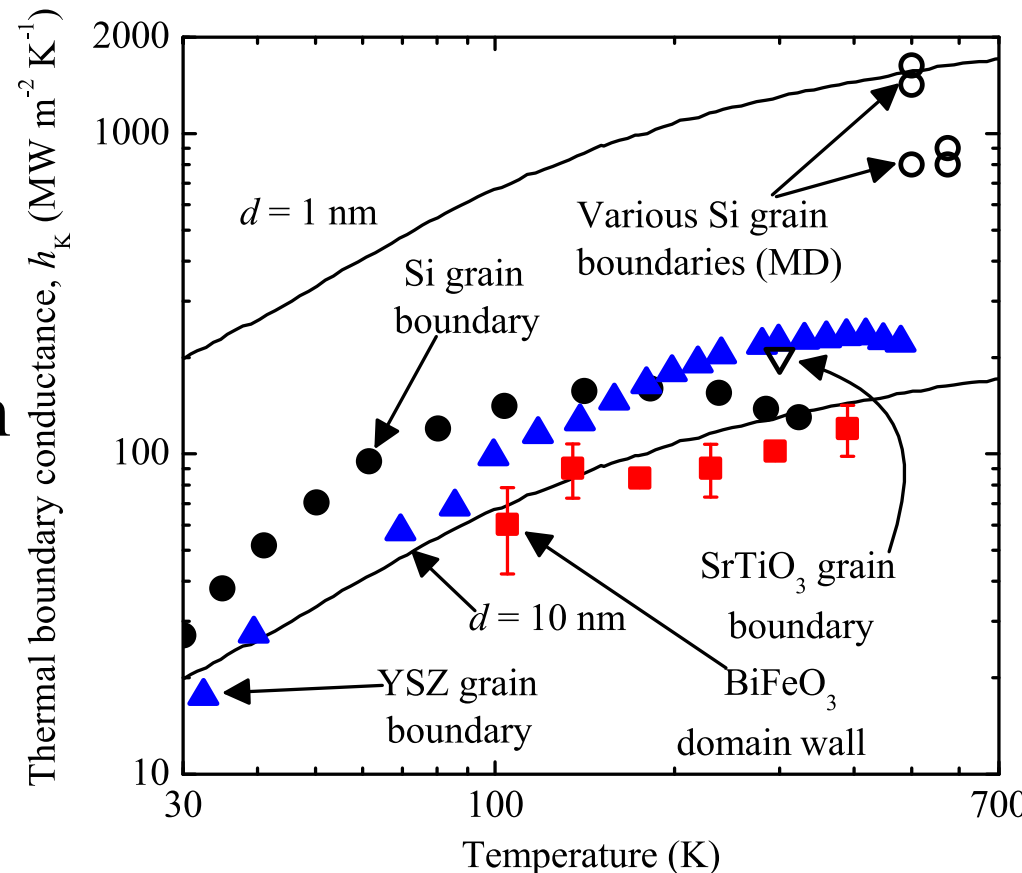


Domain effects Kapitza conductance

- **4 variant: $D = 16 \mu\text{m domain wall}/\mu\text{m}^2$**
- **2 variant: $D = 11 \mu\text{m domain wall}/\mu\text{m}^2$**

$$h_K = \frac{\kappa_0}{D \left(\frac{\kappa_0}{\kappa} - 1 \right)}$$

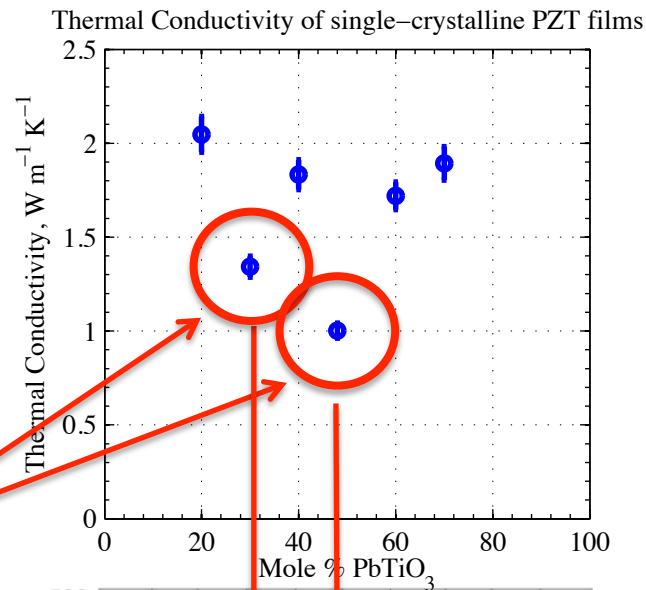
- Strain fields from coherent domain boundaries can scatter phonons like domain boundaries
- **Coherent domain walls offer as much resistance as 10 nm of SiO_2**



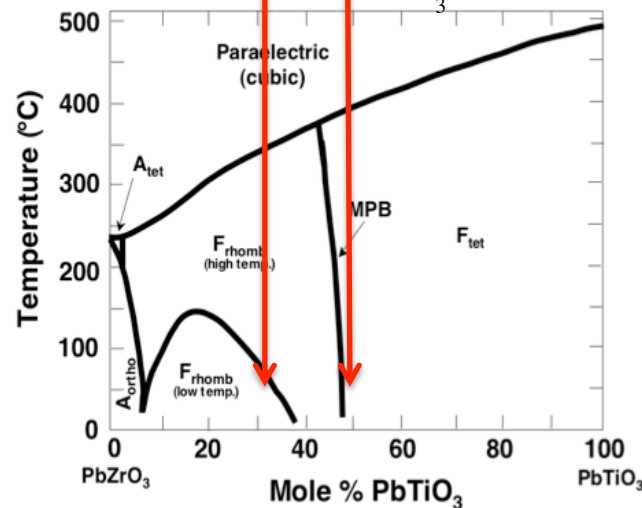
Domain engineering of thermal properties

Single Crystalline $\text{Pb}[\text{Zr}_x\text{Ti}_{1-x}]\text{O}_3$ (PZT) – A LOT OF DOMAINS!

More domains
and smaller
domains at
boundaries



**Domain scattering
stronger than
alloy scattering**



Schmitt *et al.* *JAP*
101, 074107 (2007)

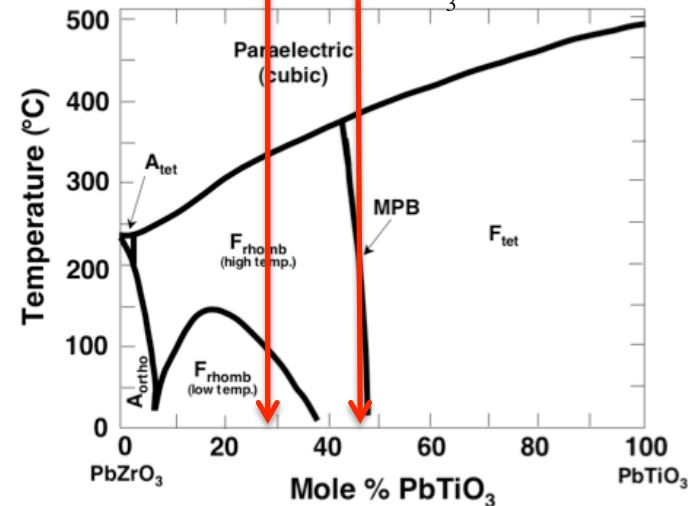
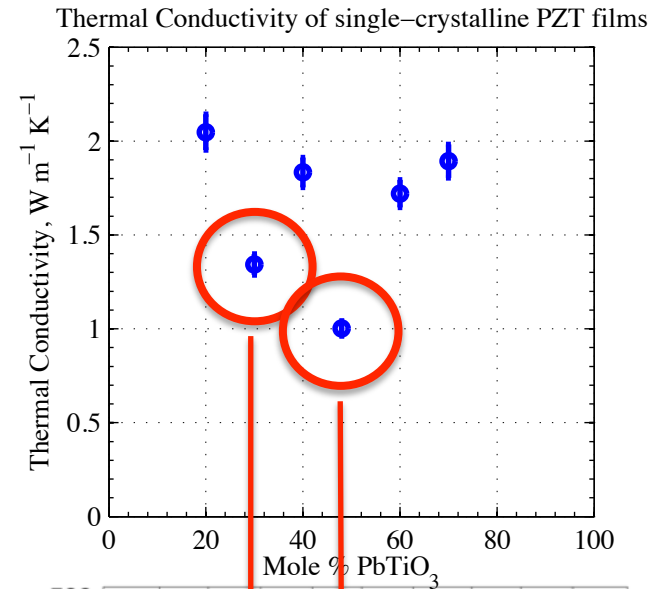
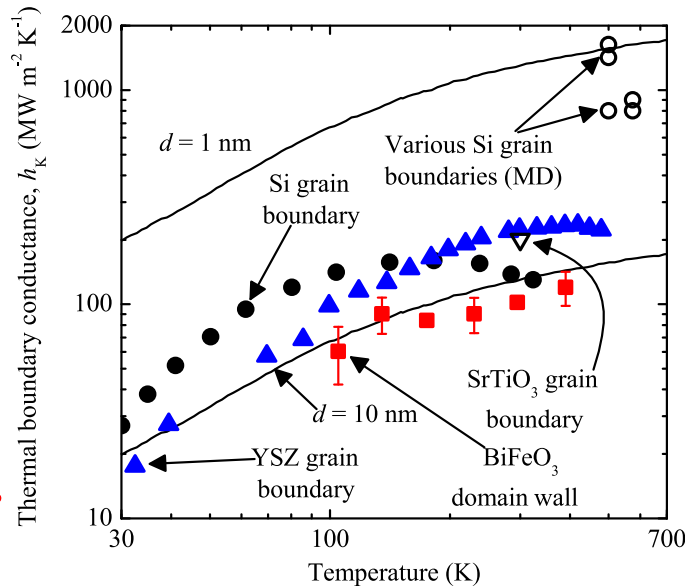
Conclusions - *Appl. Phys. Lett.* **102**, 121903 (2013)

- Domains boundaries scatter phonons
- Coherent strain fields have similar effects as incoherent grain boundaries

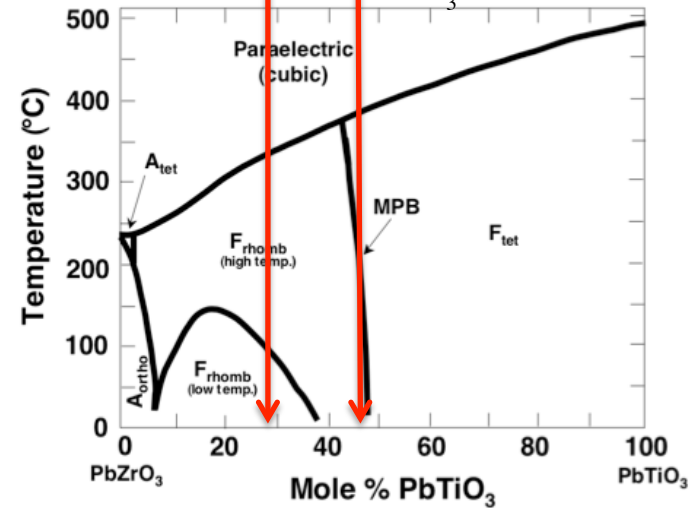
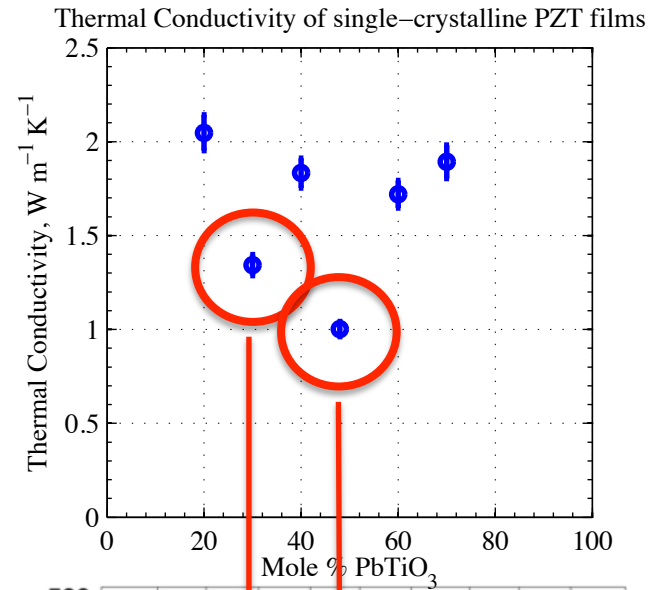
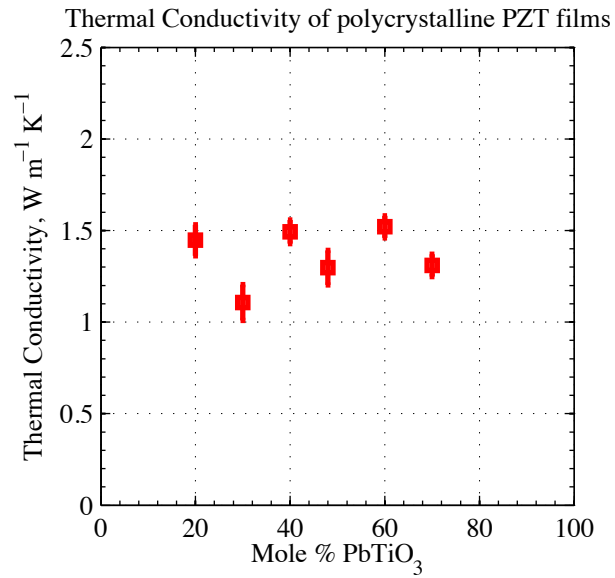
$$\frac{1}{\tau_{\text{domain wall}}} = \frac{v}{d_{\text{domain wall}}}$$



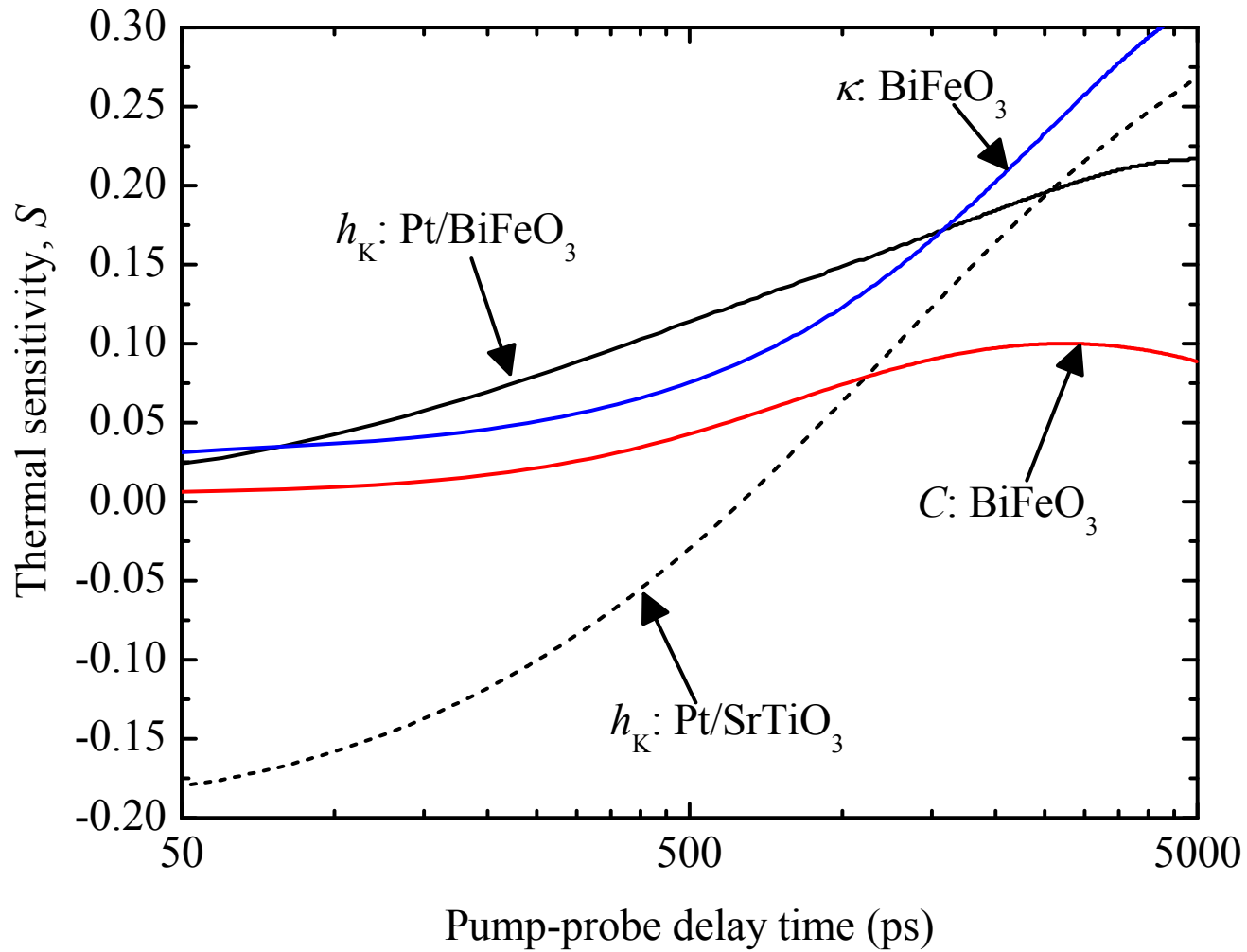
**Young Investigator
Program**



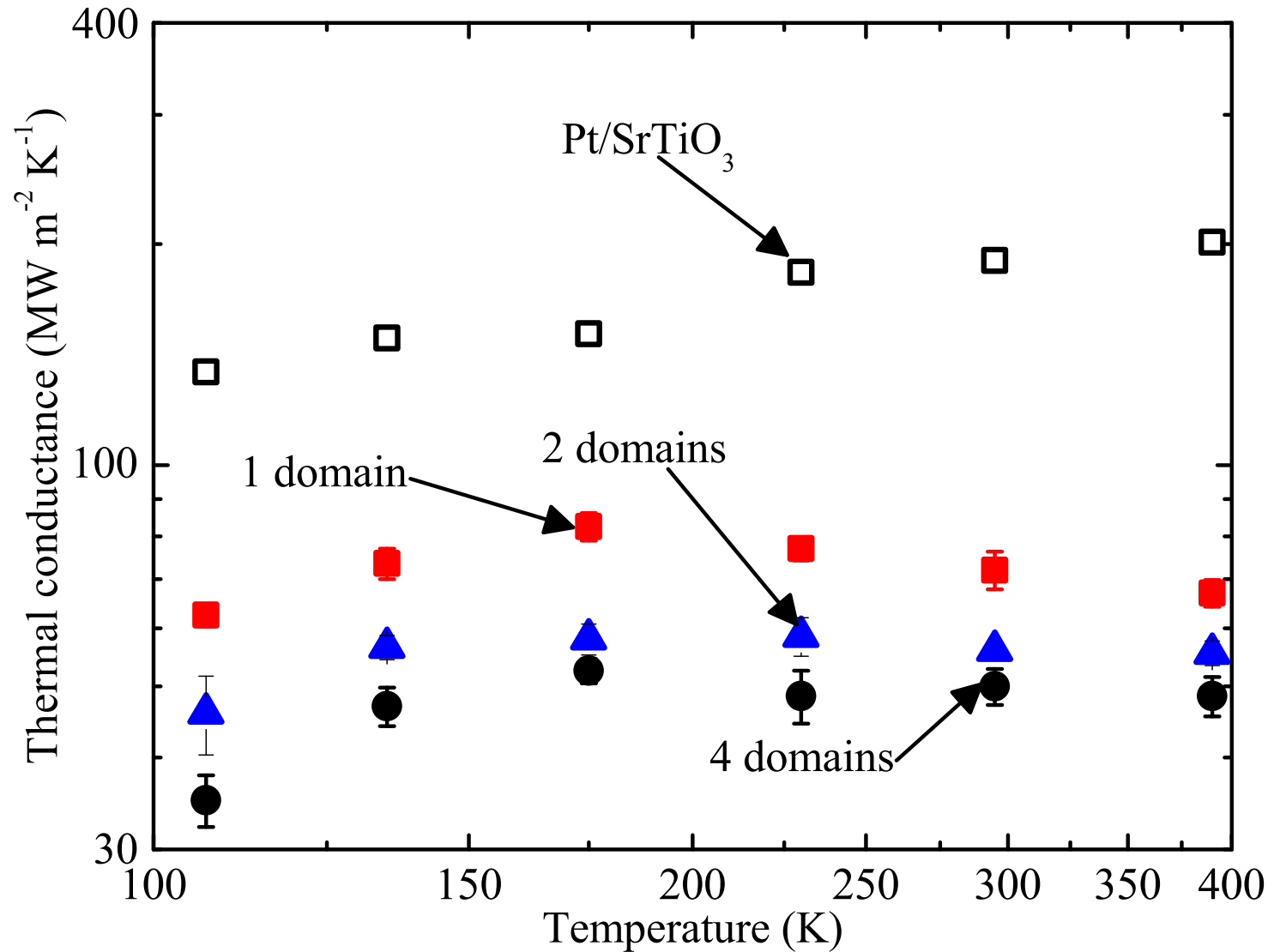
Single vs. poly PZT



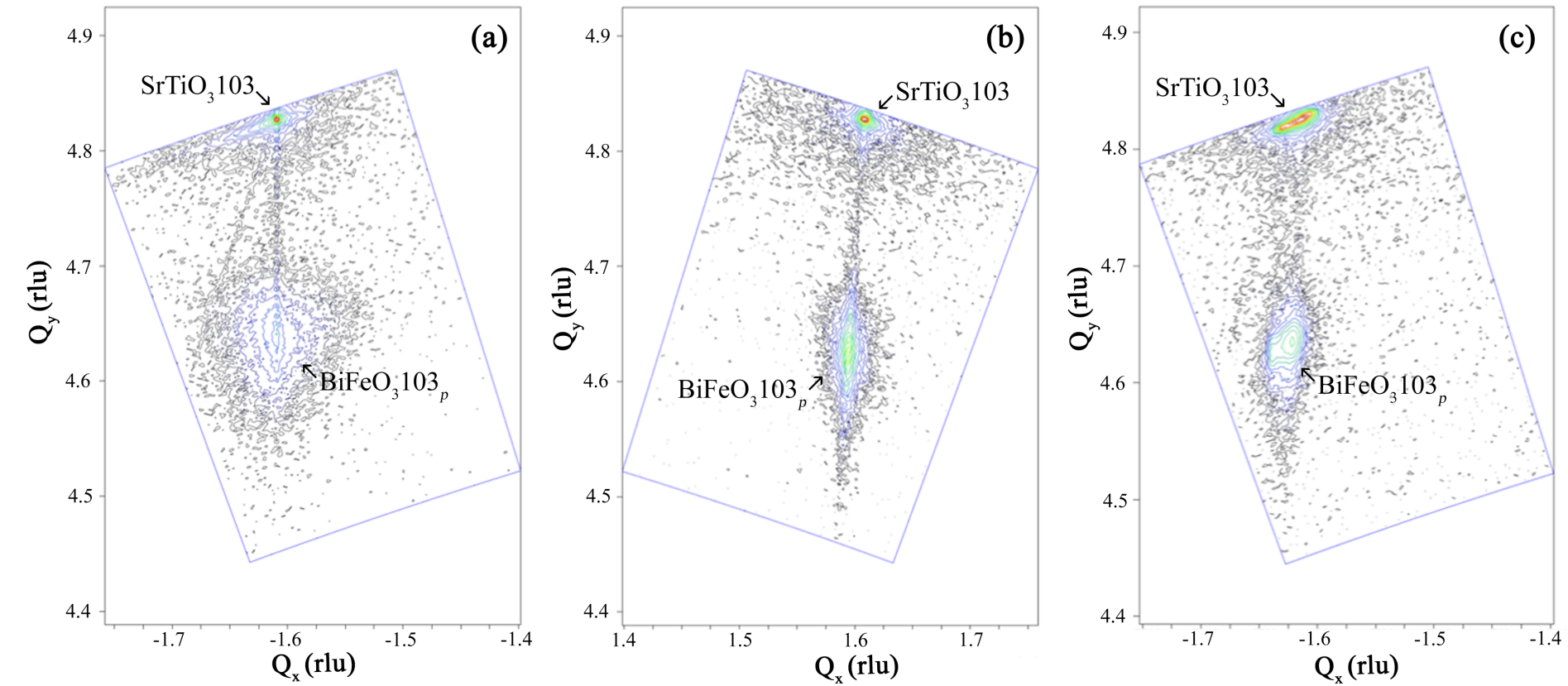
TDTR sensitivities – effective thermal conductivity



Conductance measurements



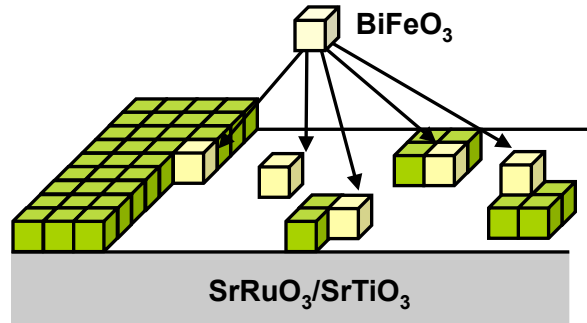
Reciprocal space mapping



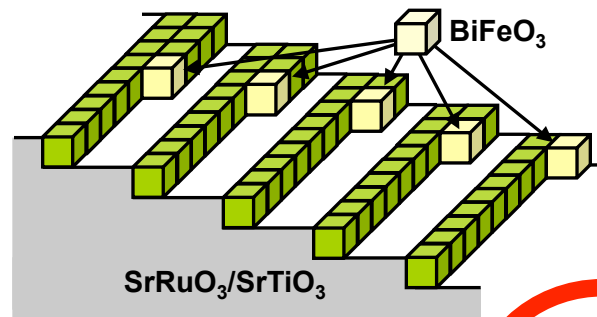
“Coherent” interfaces – Domain boundaries

- Domain boundaries – other types of coherent interfaces
- BiFeO_3 domains can be engineered with substrate vicinality

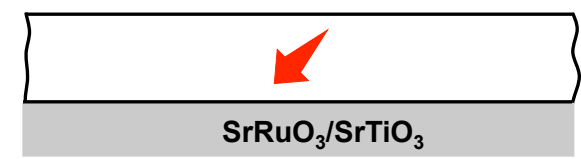
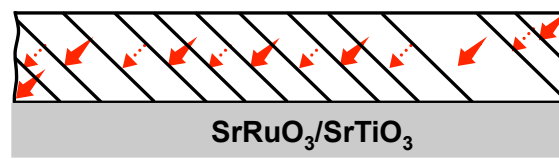
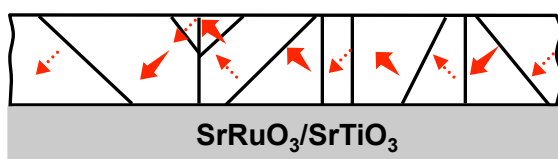
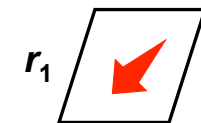
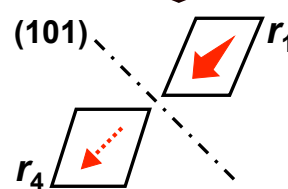
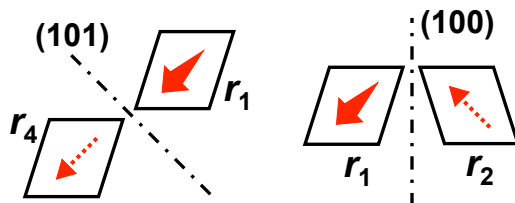
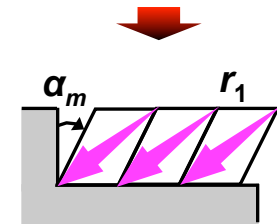
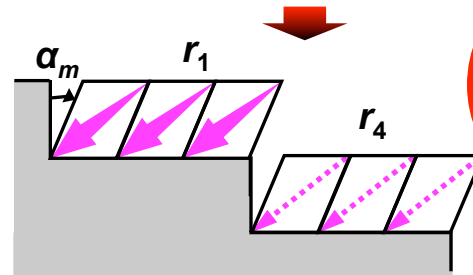
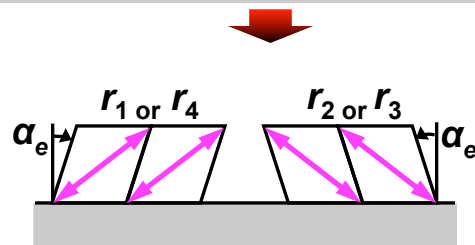
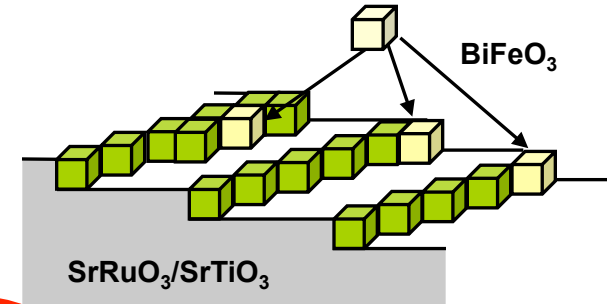
Exact (001) SrTiO_3



4° miscut toward $[100]$

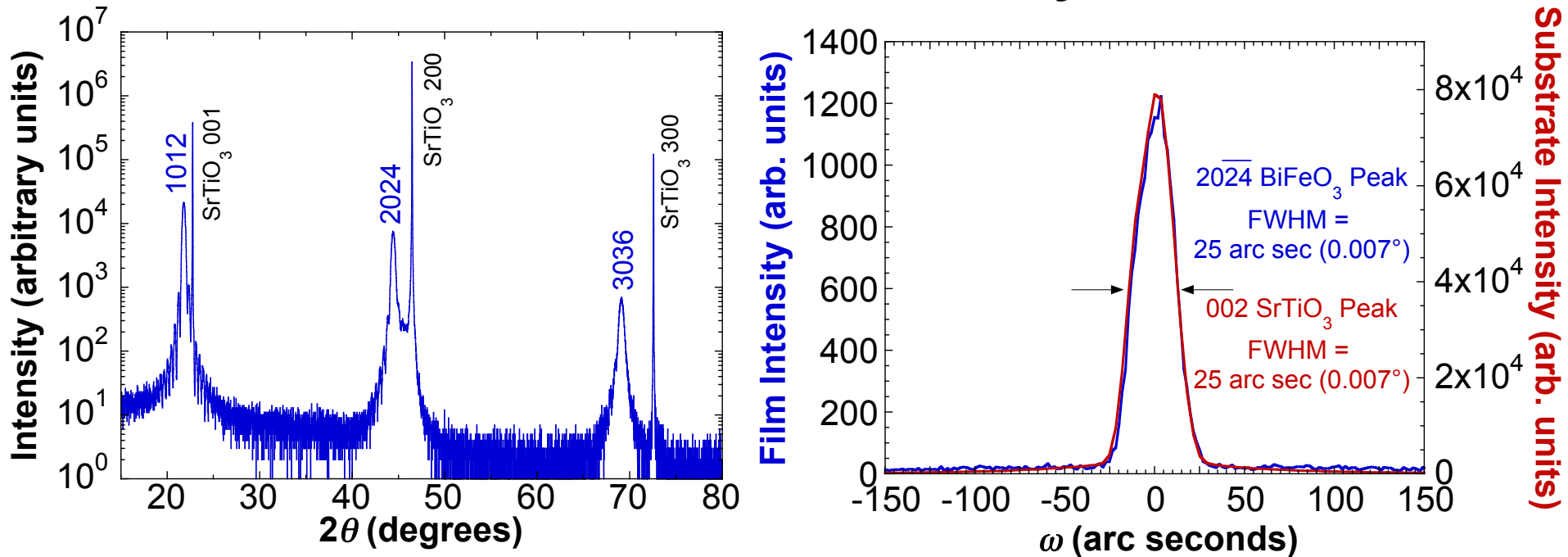


4° miscut toward $[110]$



BiFeO₃ film growth

- Reactive molecular-beam epitaxy: 30 nm BiFeO₃ films on SrTiO₃ substrates
- Phase-pure
- Smooth surface and interface
- Crystallinity limited by substrate (SrTiO₃)



Does this make sense?

- Coherent domain wall scatters phonons like incoherent grain boundary?
- What's the mechanism???

**Attenuation
(Akhieser):**

$$\frac{1}{\tau_{\text{Akhieser}}} \propto \omega^2$$

Rayleigh:

$$\frac{1}{\tau_{\text{impurity}}} \propto \omega^4$$

**Incoherent (like a
grain boundary):**

$$\frac{1}{\tau_{\text{grain}}} \propto \frac{v}{d_{\text{grain}}}$$